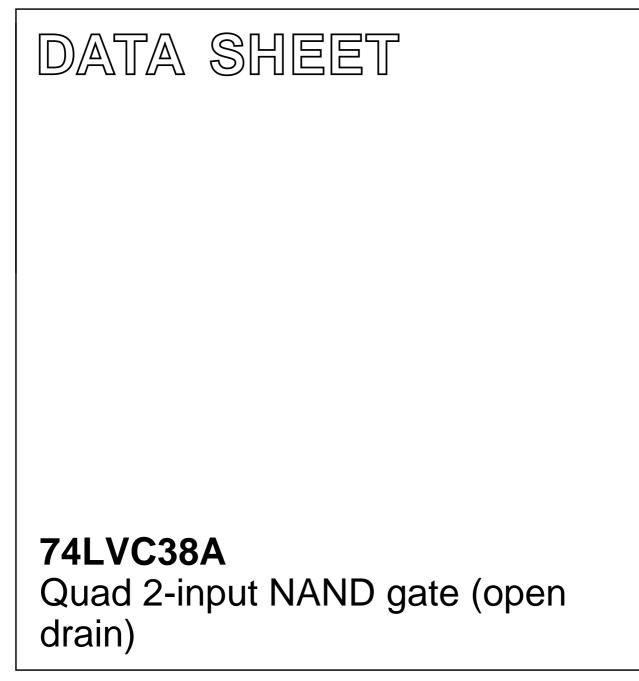
INTEGRATED CIRCUITS



Product specification Supersedes data of 2004 Mar 10 2004 Mar 22





74LVC38A

FEATURES

- 5 V tolerant inputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- Open-drain outputs
- Inputs accept voltages up to 5.5 V
- Complies with JEDEC standard no. 8-1A
- Specified from -40 to +85 °C and -40 to +125 °C.

DESCRIPTION

The 74LVC38A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 and 5 V environment.

The 74LVC38A provides the 2-input NAND function.

The outputs of the 74LVC38A devices are open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; t_r = t_f \leq 2.5 ns.

| SYMBOL | PARAMETER | CONDITIONS | TYPICAL | UNIT |
|------------------|--|---|---------|------|
| t _{PZL} | propagation delay nA, nB to nY | $C_{L} = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$ | 1.7 | ns |
| t _{PLZ} | propagation delay nA, nB to nY | $C_{L} = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$ | 2.3 | ns |
| CI | input capacitance | | 4.0 | рF |
| C _{PD} | power dissipation capacitance per gate | V_{CC} = 3.3 V; notes 1 and 2 | 5.5 | pF |

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_I = GND$ to V_{CC} .

ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | | | | | | |
|-------------|-------------------|------|----------|----------|----------|--|--|--|
| | TEMPERATURE RANGE | PINS | PACKAGE | MATERIAL | CODE | | | |
| 74LVC38AD | –40 to +125 °C | 14 | SO14 | plastic | SOT108-1 | | | |
| 74LVC38ADB | –40 to +125 °C | 14 | SSOP14 | plastic | SOT337-1 | | | |
| 74LVC38APW | –40 to +125 °C | 14 | TSSOP14 | plastic | SOT402-1 | | | |
| 74LVC38ABQ | −40 to +125 °C | 14 | DHVQFN14 | plastic | SOT762-1 | | | |

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FUNCTION TABLE

See note 1.

| INP | OUTPUTS | |
|-------|---------|----|
| nA nB | | nY |
| L | L | Z |
| L | Н | Z |
| Н | L | Z |
| Н | Н | L |

Note

1. H = HIGH voltage level;

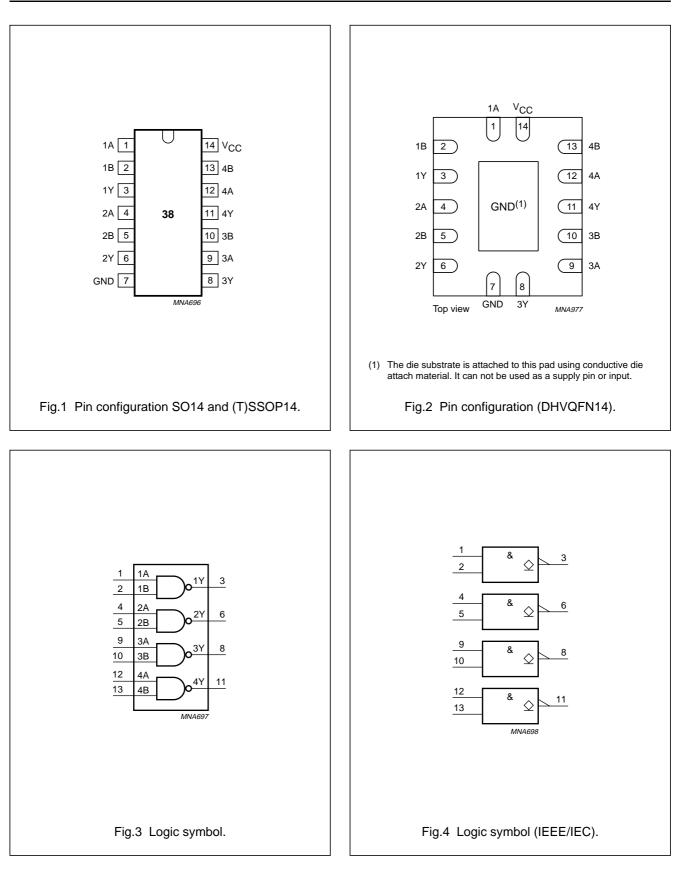
L = LOW voltage level:

Z = high-impedance OFF-state.

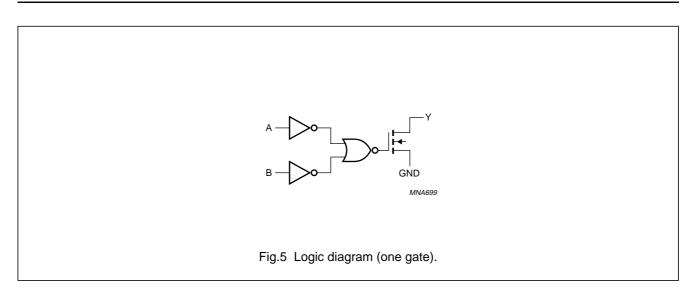
PINNING

| PIN | SYMBOL | DESCRIPTION |
|-----|-----------------|----------------|
| 1 | 1A | data input |
| 2 | 1B | data input |
| 3 | 1Y | data output |
| 4 | 2A | data input |
| 5 | 2B | data input |
| 6 | 2Y | data output |
| 7 | GND | ground (0 V) |
| 8 | 3Y | data output |
| 9 | 3A | data input |
| 10 | 3B | data input |
| 11 | 4Y | data output |
| 12 | 4A | data input |
| 13 | 4B | data input |
| 14 | V _{CC} | supply voltage |

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RECOMMENDED OPERATING CONDITIONS

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|---------------------------------|-------------------------------|--|------|------|------|
| V _{CC} | supply voltage | for maximum speed performance | 2.7 | 3.6 | V |
| | | for low-voltage applications | 1.2 | 3.6 | V |
| VI | input voltage | | 0 | 5.5 | V |
| Vo | output voltage | | 0 | 5.5 | V |
| T _{amb} | operating ambient temperature | | -40 | +125 | °C |
| t _r , t _f | input rise and fall times | $V_{CC} = 1.2 \text{ to } 2.7 \text{ V}$ | 0 | 20 | ns/V |
| | | $V_{CC} = 2.7$ to 3.6 V | 0 | 10 | ns/V |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------------------------|--------------------------------|------------------------------------|------|------|------|
| V _{CC} | supply voltage | | -0.5 | +6.5 | V |
| I _{IK} | input diode current | V ₁ < 0 | _ | -50 | mA |
| VI | input voltage | note 1 | -0.5 | +6.5 | V |
| I _{OK} | output diode current | V _O < 0 | - | -50 | mA |
| Vo | output voltage | note 1 | -0.5 | +6.5 | V |
| lo | output sink current | $V_{O} = 0$ to V_{CC} | - | 50 | mA |
| I _{CC} , I _{GND} | V _{CC} or GND current | | - | ±100 | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | power dissipation | $T_{amb} = -40$ to +125 °C; note 2 | _ | 500 | mW |

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. For SO14 packages: above 70 °C derate linearly with 8 mW/K.

For (T)SSOP14 packages: above 60 $^\circ\text{C}$ derate linearly with 5.5 mW/K.

For DHVQFN14 packages: above 60 $^\circ\text{C}$ derate linearly with 4.5 mW/K.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| SYMBOL | PARAMETER | TEST CONDITIONS | | | | | |
|------------------------|---|--|---------------------|-----------------|------|------|----|
| | | OTHER | V _{CC} (V) | MIN. | TYP. | MAX. | |
| T _{amb} = -40 |) to +85 ° C; note 1 | | I | _ | - | - | |
| V _{IH} | HIGH-level input voltage | | 1.2 | V _{CC} | - | _ | V |
| | | | 2.7 to 3.6 | 2.0 | - | _ | V |
| V _{IL} | LOW-level input voltage | | 1.2 | _ | - | GND | V |
| | | | 2.7 to 3.6 | _ | - | 0.8 | V |
| V _{OL} | LOW-level output voltage | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | | |
| | | I _O = 100 μA | 2.7 to 3.6 | _ | GND | 0.20 | V |
| | | I _O = 12 mA | 2.7 | _ | _ | 0.40 | V |
| | | I _O = 24 mA | 3.0 | _ | _ | 0.55 | V |
| ILI | input leakage current | V _I = 5.5 V or GND | 3.6 | _ | ±0.1 | ±5 | μA |
| I _{OZ} | 3-state output OFF-state | $V_{I} = V_{IH} \text{ or } V_{IL};$ | 3.6 | _ | 0.1 | ±10 | μA |
| | current | $V_0 = 5.5 V \text{ or GND}$ | | | | | |
| I _{CC} | quiescent supply current | $V_{I} = V_{CC}$ or GND; $I_{O} = 0$ | 3.6 | - | 0.1 | 10 | μA |
| ΔI_{CC} | additional quiescent supply current per input pin | $V_{I} = V_{CC} - 0.6 V; I_{O} = 0$ | 2.7 to 3.6 | - | 5 | 500 | μA |
| T _{amb} = -40 |) to +125 °C | | | | | | |
| VIH | HIGH-level input voltage | | 1.2 | V _{CC} | _ | _ | V |
| | | | 2.7 to 3.6 | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | | 1.2 | _ | _ | GND | V |
| | | | 2.7 to 3.6 | _ | - | 0.8 | V |
| V _{OL} | LOW-level output voltage | $V_{I} = V_{IH}$ or V_{IL} | | | | | |
| | | I _O = 100 μA | 2.7 to 3.6 | _ | _ | 0.3 | V |
| | | I _O = 12 mA | 2.7 | _ | _ | 0.6 | V |
| | | I _O = 24 mA | 3.0 | _ | _ | 0.8 | V |
| ILI | input leakage current | V _I = 5.5 V or GND | 3.6 | _ | - | ±20 | μA |
| I _{OZ} | 3-state output OFF-state current | $V_I = V_{IH} \text{ or } V_{IL};$ $V_O = 5.5 \text{ V or GND}$ | 3.6 | - | - | ±20 | μA |
| I _{CC} | quiescent supply current | $V_{I} = V_{CC}$ or GND; $I_{O} = 0$ | 3.6 | _ | - | 40 | μA |
| ΔI_{CC} | additional quiescent supply current per input pin | $V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0$ | 2.7 to 3.6 | - | - | 5000 | μA |

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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AC CHARACTERISTICS

 $GND = 0 V; t_r = t_f \le 2.5 ns.$

| SYMBOL | PARAMETER | TEST CONDITIONS | | | | | |
|------------------------|-------------------------------------|------------------|---------------------|--------|--------------------|------|------|
| | | WAVEFORMS | V _{CC} (V) | – MIN. | TYP | MAX. | UNIT |
| T _{amb} = -40 |) to +85 ° C ; note 1 | | | • | | | |
| t _{PZL} | propagation delay nA, nB to nY | see Figs 6 and 7 | 1.2 | - | 5.7 | - | ns |
| | | | 2.7 | 0.5 | 1.7 | 2.9 | ns |
| | | | 3.0 to 3.6 | 0.5 | 1.7 ⁽²⁾ | 3.0 | ns |
| t _{PLZ} | propagation delay nA, nB to nY | see Figs 6 and 7 | 1.2 | _ | 4.8 | _ | ns |
| | | | 2.7 | 1.0 | 2.6 | 3.8 | ns |
| | | | 3.0 to 3.6 | 1.0 | 2.3(2) | 3.6 | ns |
| t _{sk(0)} | skew | note 3 | | _ | _ | 1.0 | ns |
| T _{amb} = -40 |) to +125 °C | | • | • | | • | · |
| t _{PZL} | propagation delay nA, nB to nY | see Figs 6 and 7 | 1.2 | - | - | - | ns |
| | | | 2.7 | 0.5 | _ | 4.0 | ns |
| | | | 3.0 to 3.6 | 0.5 | _ | 4.0 | ns |
| t _{PLZ} | propagation delay nA, nB to nY | see Figs 6 and 7 | 1.2 | _ | _ | _ | ns |
| | | | 2.7 | 1.0 | _ | 5.0 | ns |
| | | | 3.0 to 3.6 | 1.0 | _ | 4.5 | ns |
| t _{sk(0)} | skew | note 3 | | - | _ | 1.5 | ns |

Notes

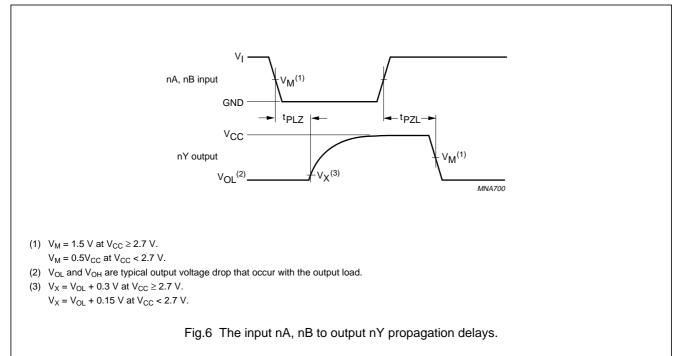
1. All typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

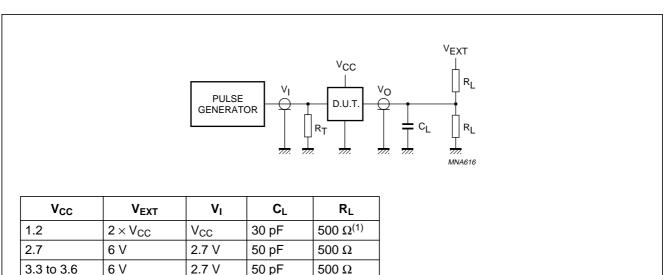
2. These typical values are measured at V_{CC} = 3.3 V.

3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

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AC WAVEFORMS





Note

1. The circuit performs better when $R_L = 1000 \Omega$.

Definitions for test circuits:

R_L = Load resistor.

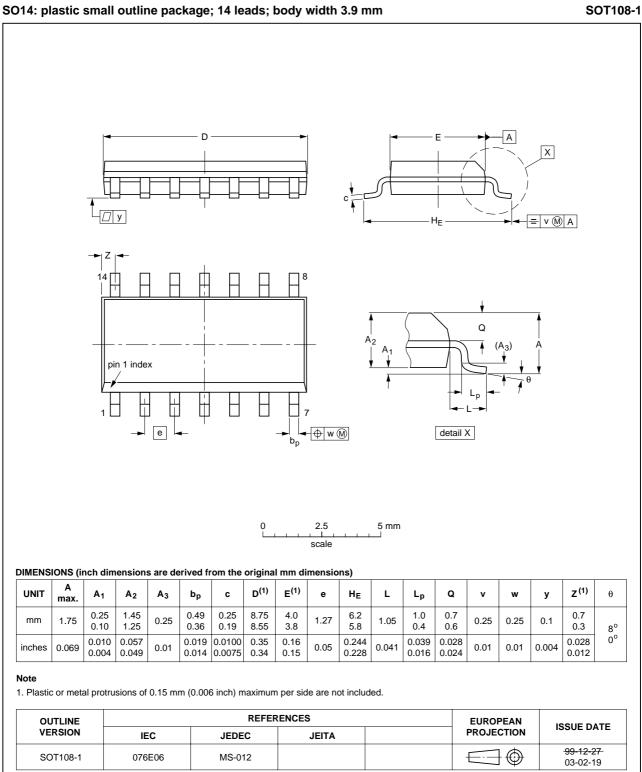
 C_{L} = Load capacitance including jig and probe capacitance.

 R_{T} = Termination resistance should be equal to the output impedance Z_{o} of the pulse generator.

 t_{r} = t_{f} \leq 2.5 ns; when measuring $f_{max},$ there is no constraint on $t_{r},\,t_{f}$ with 50% duty factor.

Fig.7 Load circuitry for switching times.

PACKAGE OUTLINES



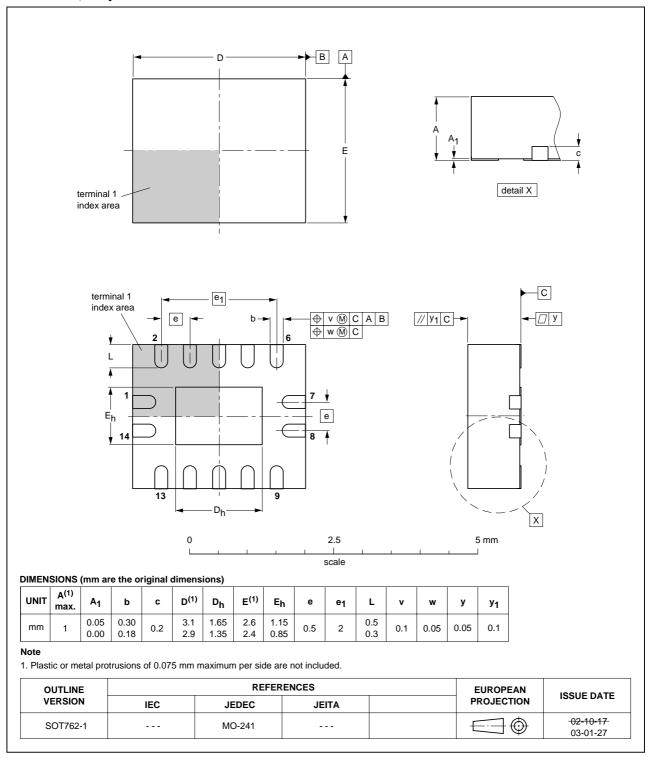
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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm SOT337-1 Α D X ____у = v M A HE -Z+ 14 🗍 Q A₂ 4 $(A_3$ pin 1 index Lp H Ш Π detail X • († w (M) ►' b_p е 2.5 5 mm 0 scale DIMENSIONS (mm are the original dimensions) Α D⁽¹⁾ E⁽¹⁾ Z⁽¹⁾ UNIT L Q θ Α₁ A_2 A_3 bp С е $H_{\rm E}$ Lp ۷ w у max 0.21 1.80 0.38 0.20 6.4 1.03 8° 5.4 7.9 0.9 1.4 2 0.13 0.1 mm 0.25 0.65 1.25 0.2 0° 0.05 1.65 0.25 0.09 6.0 5.2 7.6 0.63 0.7 0.9 Note 1. Plastic or metal protrusions of 0.25 mm maximum per side are not included. REFERENCES EUROPEAN OUTLINE ISSUE DATE VERSION PROJECTION IEC JEDEC JEITA 99-12-27 SOT337-1 MO-150 03-02-19

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm SOT402-1 А D Х = v ₪ A HE + Z 8 || Q (A_{3}) A2 A₁ pin 1 index -p detail X **-** ⊕ w M е bp 2.5 0 5 mm scale DIMENSIONS (mm are the original dimensions) Α E ⁽²⁾ D⁽¹⁾ Z ⁽¹⁾ UNIT L Q θ A_1 A₂ A₃ bp С е ${\rm H_{\rm E}}$ Lp v w у max 0.95 0.30 0.75 8° 0.15 0.2 5.1 4.5 6.6 0.4 0.72 0.65 0.2 0.1 mm 1.1 0.25 1 0.13 0.05 0.80 0.19 0.1 4.3 6.2 0.50 0.3 0° 4.9 0.38 Notes 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included. 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included. REFERENCES EUROPEAN OUTLINE **ISSUE DATE** VERSION PROJECTION IEC JEDEC JEITA 99-12-27 SOT402-1 MO-153 03-02-18

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

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DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾⁽³⁾ | DEFINITION |
|-------|-------------------------------------|-------------------------------------|--|
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